L Numbe	_	1	DB	Time stamp
1	2	2 ("6168991").PN.	USPAT;	2002/07/12 13:0
			US-PGPUB;	2002/0//12 13:0
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
2	2	? ("6211005").PN.	USPAT;	2002/07/22
				2002/07/12 14:0
			US-PGPUB;	
			EPO; JPO;	1
			DERWENT;	
3	- O	("adhesion near3 tungsten near3 (indium	IBM_TDB	
		oxide or ito)").PN.	USPĀT;	2002/07/12 14:0
		oniae of feo, j.fn.	US-PGPUB;	
	1		EPO; JPO;	ļ
			DERWENT;	
4	41	adhogion noon?	IBM_TDB	
-	4.		USPAT;	2002/07/12 14:0
		oxide or ito)	US-PGPUB;	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1
			EPO; JPO;	
			DERWENT;	
c	_		IBM TDB	
5	0		USPAT;	2002/07/10 14 1
	-	oxide or ito)	US-PGPUB;	2002/07/12 14:10
			EPO; JPO;	
			DERWENT;	1
6	0	adhesion near6 tungsten near6 (indium adj	IBM_TDB	
		oxide or ito)	USPAT;	2002/07/12 14:10
	1	Oxide of ico)	US-PGPUB;	1
			EPO; JPO;	J
			DERWENT;	
7	_	- 11 - 140	IBM TDB	
,	0	I would be the treated controlled the different the same	USPAT;	2002/07/12 14:16
		oxide or ito)	US-PGPUB;	2002/0//12 14.10
			EPO; JPO;	
			DERWENT;	
_			IBM TDB	ł
3	0	tungsten near3 (plug or contact) near6	USPAT;	2000/07/10 11
	Ť.	(indium adj oxide or ito) and dram.ti,ab.		2002/07/12 14:17
		and dram. cr, ab.	US-PGPUB;	1
			EPO; JPO;	1
	ł l		DERWENT;	)
)	2	tungsten near3 (indium adj oxide or ito)	IBM_TDB	Į
	_	and dram.ti,ab.	USPAT;	2002/07/12 15:44
		and dram.cr, ap.	US-PGPUB;	
			EPO; JPO;	
	İ		DERWENT;	
.0		tunmakan a Gallani	IBM TDB	
-	2	tungsten near6 (indium adj oxide or ito)	USPAT;	2002/07/12 15:45
		and dram.ti,ab.	US-PGPUB;	-302, 3., 12 13.43
			EPO; JPO;	ļ
			DERWENT;	
,	İ		IBM TDB	
1	2	tungsten near12 (indium adj oxide or ito)	USPAT;	2002/07/10 15
1		and dram.ti,ab.		2002/07/12 15:45
Ţ		•	US-PGPUB;	
J			EPO; JPO;	
ſ			DERWENT;	
2	494	tungsten near12 (indium adj oxide or ito)	IBM_TDB	
		oxide or ito)	USPAT;	2002/07/12 15:46
			US-PGPUB;	
	ļ		EPO; JPO;	
ļ			DERWENT;	
3		A	IBM TDB	
1	1	tungsten near12 (indium adj oxide or ito)	USPAT;	2002/07/12 15:47
ł		near12 (adhere or adhesion)	US-PGPUB;	2002/01/12 15:4/
ļ	ļ	,	EPO; JPO;	
İ			DEDWENT	
1	1		DERWENT;	
1	1	tungsten near12 (indium adj oxide or ito)	IBM_TDB	
J	- ],	near12 (adhere or adhere "	USPAT;	2002/07/12 16:03
	[ '	near12 (adhere or adhesion or adhesive)	US-PGPUB;	
1			EPO; JPO;	
			DERWENT;	
			IBM TDB	

15	1	(w or tungsten) near12 (indium adj oxide or ito) near12 (adhere or adhesion or	USPAT; US-PGPUB;	2002/07/12 16:23
		adhesive)	EPO; JPO; DERWENT; IBM TDB	
16	21	(w or tungsten) near12 (prevent or	USPAT;	2002/07/12 16:36
	Ì	preventing) near12 oxidation near12	US-PGPUB;	
		(contact or plug)	EPO; JPO;	
			DERWENT; IBM TDB	
17	1	(prevent or preventing) near12 oxidation	USPAT;	2002/07/12 16:49
		near12 indium adj oxide	US-PGPUB;	2002/01/12 10:45
			EPO; JPO;	
			DERWENT; IBM TDB	
18	7	i ( carroundam ada) michilaco Or cam, meditiz	USPAT;	2002/07/12 16:53
		(tungsten or w) near12 (indium adj oxide	US-PGPUB;	2552,51,12 10105
		or ito or indium adj tin adj oxide)	EPO; JPO;	
			DERWENT; IBM TDB	
19	530	1 ( The same and series of carry nearly	USPAT;	2002/07/12 16:53
1		(tungsten or w) near12 (barrier or	US-PGPUB;	
		passivation)	EPO; JPO;	
			DERWENT; IBM TDB	
20	53	( day may made do de cam, modes	USPAT;	2002/07/12 16:54
İ		(tungsten or w) near3 (barrier or	US-PGPUB;	2002, 07, 22 20101
		passivation)	EPO; JPO;	
	,		DERWENT; IBM TDB	
21	5	(tantalum adj nitride or tan) near3	USPAT;	2002/07/12 16:58
		(tungsten or w) near3 (barrier or	US-PGPUB;	20.00
		passivation).ti,ab.	EPO; JPO;	
			DERWENT; IBM TDB	
22	135	(tantalum adj nitride or tan) near3	USPAT;	2002/07/12 17:18
		(tungsten or w).ti,ab.	US-PGPUB;	2002/01/22 27:10
			EPO; JPO;	
			DERWENT; IBM TDB	
23	8	(tantalum adj nitride or tan) near3	USPAT;	2002/07/12 17:26
		(tungsten or w).ti.	US-PGPUB;	
			EPO; JPO; DERWENT;	
	[		IBM TDB	
24	277	(tantalum adj nitride or tan) near3	USPĀT;	2002/07/12 17:27
	1	(tungsten or w) near12 barrier	US-PGPUB;	
			EPO; JPO; DERWENT;	
0.5			IBM TDB	
25	18	(tantalum adj nitride or tan) near3	USPAT;	2002/07/12 19:16
		(tungsten or w) near12 barrier.ti,ab.	US-PGPUB;	
			EPO; JPO; DERWENT;	
			IBM TDB	
26	0	(tantalum adj nitride or tan) near3	USPAT;	2002/07/12 18:08
[		(indium adj2 oxide or ito) near12 barrier.ti,ab.	US-PGPUB;	
			EPO; JPO; DERWENT;	
	_		IBM TDB	
27	2	("6265260").PN.	USPAT;	2002/07/12 19:17
	ŀ		US-PGPUB;	
			EPO; JPO; DERWENT;	
00			IBM_TDB	
28	2	("6168991").PN.	USPĀT;	2002/07/12 19:39
	1		US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	

29	0	("oxidation adj potential near12 (tungster or W)").PN.		2002/07/12 19:3
		or wy ).PN.	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
30	55	Table 1 and potential nearly (tungsten	IBM_TDB USPAT;	2002/07/10 10
		or W)	US-PGPUB;	2002/07/12 19:4
			EPO; JPO;	
			DERWENT;	
_	6085	//257/69) on /257/71)	IBM TDB	
	0005	((257/68) or (257/71) or (257/296) or (257/300) or (257/306) or (257/308) or	USPAT;	2002/07/12 12:5
		(257/309) or (257/310) or (257/311) or	US-PGPUB;	
		(257/761) or (257/763) or (361/303) or	EPO; JPO;	
		(361/305) or $(361/306.1)$ or $(361/306.3)$ or	DERWENT;	
_		(361/311)).CCLS.	IBM_TDB	
-	23	1 *** 2017 00 7 01 1 2017 11 1 01 1 1 2 1 7 2 1 7 2 1 8 1 1	USPAT;	2001/08/23 08:4
ŀ		or ("25//300") or ("257/306") or	US-PGPUB;	2001/00/23 08:40
		("257/308") or ("257/309") or ("257/310")	EPO; JPO;	
İ		or ("257/311") or ("257/761") or	DERWENT;	
		("257/763") or ("361/303") or ("361/305") or ("361/306.1") or ("361/306.3") or	IBM_TDB	
		("361/311")).CCLS.) and semiconductor and		
		capacitor and (tantalum adi oxide or		
		tantalum adj pentoxide) and tantalum adi		
}	_	nitride and tungsten and substrate		
•	0	6285072.pn.	JPO;	2001/08/22 18:20
	3	///8057/608	DERWENT	2001/00/22 10:20
	3	((("257/68") or ("257/71") or ("257/296")	USPAT;	2001/08/22 20:49
1		or ("257/300") or ("257/306") or ("257/308") or ("257/308")	US-PGPUB;	
		("257/308") or ("257/309") or ("257/310") or ("257/311") or ("257/761") or	EPO; JPO;	
	1	("257/763") or ("361/303") or ("361/305")	DERWENT;	
	j	01 (361/306.1'') or $("361/306.3")$ or	IBM_TDB	
		("361/311")).CCLS.) and semiconductor and		
		capacitor and (tantalum adi oxide or		
ŀ		tantalum adj pentoxide) and indium adj		
	2	oxide and tungsten and substrate		
1	2	((("257/68") or ("257/71") or ("257/296")	USPAT;	2001/08/23 08:49
1	j	or ("257/300") or ("257/306") or ("257/308") or ("257/309") or ("257/310")	US-PGPUB;	
1	1	or ("257/311") or ("257/761") or	EPO; JPO;	
	1	("257/763") or $("361/303")$ or $("361/305")$	DERWENT;	
		or ("361/306.1") or ("361/306.3") or	IBM_TDB	
		("361/311")).CCLS.) and semiconductor and	,	
	1	Capacitor and (tantalum adi oxide or		
		tantalum adj pentoxide) and indium adj		
		oxide and tungsten and substrate and tantalum adj nitride		
1	0	Semiconductor and consists and a		
ĺ	Ĭ,	semiconductor and capacitor and (tantalum adj oxide or tantalum adj pentoxide) and	EPO; JPO;	2001/08/23 08:47
	1	tantalum adj nitride and tungsten and	IBM_TDB	
	1	substrate		
	8   3	semiconductor and capacitor and (tantalum	USPAT;	2001/00/02 00 :-
	۰ ا	d) oxide or tantalum adi pentovide) and	US-PGPUB;	2001/08/23 08:48
1	-	indium adjoxide and tungsten and	EPO; JPO;	
1	5	substrate and tantalum adj nitride	DERWENT;	
	0   5	semi conductor and asset	IBM TDB	
	٦	semiconductor and capacitor and (tantalum	EPO; JPO;	2001/08/23 08:48
}	i	ndj oxide or tantalum adj pentoxide) and indium adj oxide and tungsten and	DERWENT;	
	1 7	substrate and tantalum adj nitride	IBM TDB	

-		2 ((("257/68") or ("257/71") or ("257/296")	USPAT;	2001/08/23 08:5
		or ("257/300") or ("257/306") or	HC DCDHD	.   2001/08/23 08:5
,		("257/308") or $("257/309")$ or $("257/310")$	EPO; JPO;	
ļ		or ("25//311") or ("257/761") or	DEDMENE.	<b>'</b>
	İ	("257/763") or $("361/303")$ or $("361/305")$		
		or ("361/306.1") or ("361/306.3") or	IBM_TDB	
		("361/311")).CCLS.) and semiconductor and		
		capacitor and (tantalum adj oxide or		
		tantalum adj pentoxide) and indium adj		
		oxide and substrate and tantalum adj		
		nitride		1
_				i
		The same domain and capacition and transaction	EPO; JPO;	2001/08/23 08:5
		adj oxide or tantalum adj pentoxide) and	IBM_TDB	111,20 00.0
		indium adj oxide and substrate and	_	
_	1	tantalum adj nitride	İ	
	'	semiconductor and (capacitor or dram) and	EPO; JPO;	2001/08/23 08:5
		(tantalum ad) oxide or tantalum adi	IBM TDB	2001/08/23 08:5
	;	pentoxide) and indium add oxide and	1011_100	
		tantalum adj nitride		}
-	0	(tantalum adj nitride with work adj	USPAT;	2001 (00 (00
	1	function) and semiconductor and dram and		2001/08/23 10:38
	ĺ	capacitor	US-PGPUB;	1
		_	EPO; JPO;	
	1		DERWENT;	1
-	1	(tantalum adj nitride with work adj	IBM_TDB	
	_	function) and somiconducts	USPAT;	2001/08/23 10:40
		function) and semiconductor and capacitor	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
_	10	(A	IBM TDB	
	12		USPAT;	2001/08/23 10:41
	5	function) and (257/\$5.ccls. or	US-PGPUB;	2001/00/25 10.41
		438/\$5.ccls.)	EPO; JPO;	
			DERWENT;	1
			IBM TDB	
_	3	4663559.pn.		0001 (00 (00
		•	USPAT;	2001/08/23 11:16
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
-	0	barrier with tantales and mitters	IBM_TDB	
		barrier with tantal\$2 adj nitride with ev	USPAT;	2001/08/23 11:47
	1		US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
	500		IBM TDB	
	522	barrier with tantal\$2 adj nitride	USPAT;	2001/08/23 11:47
	J i		US-PGPUB;	-301/00/23 11:4/
			EPO; JPO;	
	İ		DERWENT;	
			IBM TDB	1
	141	diffusion adj barrier with tantal\$2 adj	USPAT;	2001/00/03
ľ		nitride salar santaive adj		2001/08/23 11:47
			US-PGPUB;	
}			EPO; JPO;	
	ļ		DERWENT;	
ļ	0	diffusion adj barrier with tantal\$2 adj	IBM_TDB	1
1	-	nitride with work adj function	USPAT;	2001/08/23 11:48
1	J	with work adj function	US-PGPUB;	
ſ	ĺ		EPO; JPO;	
			DERWENT;	ĺ
İ	_	alse.	IBM TDB	
	U	diffusion adj barrier with tantal\$2 adj	USPAT;	2001/08/23 11:48
. ]	J	nitride same work adj function	US-PGPUB;	2001/00/23 11:48
			EPO; JPO;	
İ	1			
1	1		DERWENT;	ļ
1	0	(diffusion adj barrier with tantal\$2 adj	IBM_TDB	
	-	nitride) same work adj function	USPAT;	2001/08/23 11:48
į			US-PGPUB;	
į	1	İ	EPO; JPO;	}
		}	DERWENT;	1
			IBM TDB	;

-		(diffusion adj barrier with tant\$4 adj	USPAT;	2001/08/23 11:49
		nitride) same work adj function	US-PGPUB;	2001/08/23 11:49
		_	EPO; JPO;	
			DERWENT;	
_		(diffusion add barrier with tantes and	IBM TDB	
	-		USPAT;	2001/08/23 12:06
		nitride) and (tant\$4 adj nitride same work adj function)		
		adj Tanceton,	EPO; JPO;	
			DERWENT;	
-		diffusion adj barrier with tant\$4 adj	IBM_TDB USPAT;	2001/00/02 10 05
	ĺ	nitride with indium adj oxide	US-PGPUB;	2001/08/23 12:06
			EPO; JPO;	
			DERWENT;	,
_	3	/ALEE-LL N. N. N.	IBM TDB	
	3		USPAT;	2001/08/23 12:38
		nitride) and (semiconductor.ti,ab. and capacitor.ti,ab.)	US-PGPUB;	
	İ	capacitor.tr, ab.)	EPO; JPO;	
			DERWENT;	
•	1	1 (= 44,149 44) CULLETTE WILL LATE SA AND	IBM_TDB USPAT;	2001/00/02 10
		nitride) and (semiconductor tilab and	US-PGPUB;	2001/08/23 12:42
	1	capacitor.ti,ab.)	EPO; JPO;	
	1		DERWENT;	1
	17		IBM TDB	
	17	T TO THE PARTY OF	USPAT;	2001/08/23 12:52
	ł	(semiconductor.ti,ab. and capacitor.ti,ab.)	US-PGPUB;	
		capacitor.ti,ab.)	EPO; JPO;	
			DERWENT;	
	2	jp-10320569\$-\$.did.	IBM_TDB	
			JPO; DERWENT	2001/08/23 19:32
	626	effective adj refractive adj index	JPO;	2001/08/23 19:33
			DERWENT	2001/08/23 19:33
	99	orrestric adj refractive ad   index near!()	JPO;	2001/08/23 19:33
	61	mode	DERWENT	= 01, 00, 23 13.33
	01	effective adj refractive adj index near4 mode	JPO;	2001/08/23 19:34
	310	effective adj refractive adj index near4	DERWENT	
		mode	USPAT;	2001/08/23 19:34
			US-PGPUB; EPO;	
			DERWENT;	!
			IBM TDB	1
	26		USPAT;	2001/08/23 19:34
		waveguide adj mode	US-PGPUB;	2001/00/25 19:54
	1		EPO;	
	}		DERWENT;	
	6349	((257/68) or (257/71) or (257/296) or	IBM_TDB	
	55.15	(257/300) or (257/306) or (257/308) or	USPAT;	2001/12/10 13:36
		(257/309) or (257/310) or (257/311) or	US-PGPUB;	
		(257/761) or (257/763) or (361/303) or	EPO; JPO;	
ľ	}	(361/305) or $(361/306.1)$ or $(361/306.3)$ or	DERWENT; IBM TDB	
		(361/311)).CCLS.	100-100	
	0	("L4 and (indium adj2 oxide near10	USPAT;	2001/12/10 13:39
		(storage or first or second or cell) adda	US-PGPUB;	2001/12/10 13:39
		Alactrodoll") Di	EPO; JPO;	
			DERWENT;	
	1	1//257/608) (8057/748)	IBM_TDB	İ
	*		USPAT;	2001/12/10 13:43
ĺ		("257/309") on ("257/200")	US-PGPUB;	
			EPO; JPO;	ļ
	1	("257/763") or ("261/202")	DERWENT;	
	I	or ("361/306.1") or ("361/306.3") or	IBM_TDB	
	i	("361/311")).CCLS.) and (indium adia ovide		
	1	nearlU (storage or first or second or		
	1	cell) adj2 electrode)	1	1

	6 ((("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/306") or		2001/12/10 14:0
	("257/308") or ("257/306") or ("257/310")	US-PGPUB;	;
	101 (237/311") or ("257/761") or		:
	("25//763") or $("361/303")$ or $("361/305")$	DERWENT;	
	1 0 1 0 301/300.1") or ("361/306 3") or	_	
	("301/311")). CCLS.) and (indiam add) and		
	same (Storage or first or second or coll)		
_	adjz electrode)	1	
	9 ((("257/68") or ("257/71") or ("257/296")	USPAT;	2001/12/10 14:51
	1 01 ( 237/300") or ("257/306") or	US-PGPUB;	2001/12/10 14:5
	("257/308") or ("257/309") or ("257/310")	EPO; JPO;	1
	or ("257/311") or ("257/761") or	DERWENT;	ĺ
	("257/763") or ("361/303") or ("361/305") or ("361/306.1") or ("361/306.3") or	IBM_TDB	
	("361/311")).CCLS.) and (indium adj oxide	_	ļ
	same electrode) and capacitor.ti,ab.		
-	1 ((("257/68") or ("257/71") or ("257/296")		
	$\frac{1}{1}$ $\frac{1}$	USPAT;	2001/12/10 15:17
	("25//308") or $("257/309")$ on $("257/309")$	US-PGPUB;	
	1	EPO; JPO;	
	("25//63") or $("361/303")$ or $("361/305")$	DERWENT;	1
	1 0 1 0 201/300,1") Or ("361/306 3") on	IBM_TDB	
	( Joi/Jii")).CCLS.) and (nurnose same	1	
	Indian ad Oxide same electrodo) and		
_	Capacitor, ti, ab.		
	- 1 111 2077 00 7 OI 1 2077/1111 Or 71087/2001	USPAT;	2001/12/10 15:06
	or ("257/300") or ("257/306") or ("257/308")	US-PGPUB;	1201/12/10 15:06
	("257/308") or ("257/309") or ("257/310") or ("257/311") or ("257/761") or	EPO; JPO;	
	("257/763") or ("361/303") or ("361/305")	DERWENT;	1
	or ("361/306.1") or ("361/306.3") or	IBM_TDB	
	("361/311")).CCLS.) and (purpose same		1
	Indian ad Oxide same electrode)		Į
-	$0 \mid (("25//68") \text{ or } ("257/71") \text{ or } ("257/296")$		
	1 1 1 (23//300") or ("257/306") or	USPAT;	2001/12/10 15:10
	("25//308") or $("257/309")$ or $("257/3108")$	US-PGPUB;	
		EPO; JPO; DERWENT;	
	("25)//63") or $("361/303")$ or $("361/305")$	IBM TDB	1
	0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0 0	12011_100	1
į	( Sol/Sil")).CCLS.) and ((tungston on a)		
ł	Hear4 (prud or Via)) and (electrode some		1
1	Indian dd   Oxide   and (dieloctric10		
j	(tantalum adj oxide or tantalum adj		
1	pentoxide)) and (capacitor or dram)ti,ab.		
	0 ((("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/306") or	USPAT;	2001/12/10 15:13
	("257/308") or ("257/306") or ("257/310")	US-PGPUB;	
	101 (23//311") or ("25//761") or	EPO; JPO;	
	("257/763") or $("361/303")$ or $("361/305")$	DERWENT;	
	1 0 1 0 1 1 0 1 0 1 1 0 1 1 1 1 0 1 0 1	IBM_TDB	
1	$(V_{\text{301/311}})$ ).CCLS.) and $(V_{\text{tungeton on } M})$		
	Heart (plug Or Via)) and (electrode		
1	Indian ad Oxide) and ((insulating on		
	insulator or dielectric) near10 (tantal )		
	adj Oxide Of tantalim adi pentovido.		
1	(capacitor or dram or electrodo) +:	ŀ	
	$\circ$ (111 257/08") or ("257/71") or ("257/206")	USPAT;	2001/12/10 15:14
	102 (237/300°) Or ("257/306") on	US-PGPUB;	112:14
}	("257/308") or ("257/309") or ("257/310")	EPO; JPO;	
	194 ( 437/311") Or ("257/761") on	DERWENT;	
	("257/763") or ("361/303") or ("361/305")	IBM TDB	
	1 0 1 1 3 0 1 / 3 0 0 . 1 " 1 Or 1 " 3 6 1 / 3 0 6 3 # 1	-	
1	("361/311")).CCLS.) and ((tungsten or w)		
	near4 (plug or via)) and (electrode same indium adj oxide) and ((insulating or		
ĺ	insulator or dielectric) near10 (tantalum	-	
- I			

0 ((("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/31") or ("257/31") or ("257/31") or ("257/31") or ("257/31") or ("257/31") or ("361/305") or ("361/31")CCLS,) and ((tungsten or w) insulator or dielectrid (Ansulating or insulator or dielectrid (Ansulating or insulator or dielectrid) or ("257/20") or ("257/30") or ("257/30") or ("257/20") or ("257/30") or ("25					
0	-		-   (		2001/12/10 15:15
OF ("257/763") or ("361/306.3") or ("361/305") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("361/306.1") or ("257/308") or ("361/306.1") or ("257/308") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/308.1"			01 ("257/300") or ("257/306") or	US-PGPUB;	
Carter   C			(257/308") or ("257/309") or ("257/310")	EPO; JPO;	
or ("361/311"). CLIS.) and (cletrode same indium adjoxide) and (insulating or insulator or dielectric) near12 (tantalum adjoxide) and (insulating or insulator or dielectric) near12 (tantalum adjoxide) and (insulating or creation) or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/306.3") or ("361/305") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/300.3") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/300") or ("257/63") or ("			or ("257/311") or ("257/761") or	DERWENT;	
or ("361/311"). CLIS.) and (cletrode same indium adjoxide) and (insulating or insulator or dielectric) near12 (tantalum adjoxide) and (insulating or insulator or dielectric) near12 (tantalum adjoxide) and (insulating or creation) or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/306.3") or ("361/305") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/300.3") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("361/305.3") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/63") or ("257/300") or ("257/63") or ("			("25///63") or ("361/303") or ("361/305")	IBM TDB	
("361/311").CCLS.) and ((tungsten or w)   near12 (plug or via)) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide or tantalum adj pentoxide))   ("259/68") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("361/301") or ("361/306.3") or ("361/301") or ("361/306.3") or ("361/308") or ("361/3		1	or ("361/306.1") or ("361/306.3") or		
			("361/311")).CCLS.) and $((tungsten or w)$		
Indium adj oxide) and ((insulating or insulator or dielectric) nearl2 (tantalum adj oxide or tantalum adj pentoxide))  1 (("237/68") or ("257/306") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("361/305.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/308.") or ("257/68") or ("257/308") or ("2			nearly (plug or via)) and (electrode same		
Insulator or dielectric) nearl2 (tantalum adj oxide or tantalum adj pentoxide)			indium adi oxide) and ((insulating or		
adj			insulator or dielectric nearly (track)	1	
1 ((("257/36") or ("257/30") or ("257/36") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("361/301") or		ŀ	adj oxide or tantalum adj mark (tantalum	1	
OF ("257/300") or ("257/306") or ("257/301") or ("257/301") or ("257/311") or ("257/761") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/311").CCLS.) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide or tantalum adj pentoxide) or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/305.3") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("257/300") or ("361/301") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/301")	_	1	((/"257/60") on ("257/71")		
("257/309") or ("257/309") or ("257/310") or ("257/31") or ("257/31") or ("257/31") or ("257/31") or ("361/305") or ("361/306.1") or ("361/306.3") or ("361/31"). (CDLS.) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide or tantalum adj pentoxide))  ("("257/300") or ("257/306") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/305.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/301"). Or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/300")		1	or ("257/296")		2001/12/10 15:36
Or ("257/763") or ("361/306.3") or ("361/305") or ("361/306.1") or ("361/306.3") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.3") or ("257/306") or ("257/306") or ("257/306") or ("257/306") or ("257/308") or ("257/308") or ("361/303") or ("361/306.3") or ("361/306.1") or ("361/303.3") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("361/306.3") or ("361/3			("257/300") or ("25//306") or	US-PGPUB;	
C. ( (257/1763") or ("251/303") or ("361/305") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("257/306") or ("257/306") or ("257/306") or ("257/306") or ("257/306") or ("257/306") or ("361/306.1") or ("361/303)") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/306") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("361/306.3") or ("361/306.3") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("257/308") or ("361/306.3") or (		1	("257/300") or ("257/309") or ("257/310")	EPO; JPO;	
("35/7/30") or ("361/306.1") or ("361/306.1") or ("361/311"). CCLS.) and (electrode same indium adj oxide) and (insulating or insulator or dielectric) nearl2 (tantalum adj oxide) or tantalum adj pentoxide) ((("257/66") or ("257/306") or ("257/308") or ("257/309") or ("257/308") or ("257/309") or ("257/30") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("257/767) or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/306.1") or ("257/300") or ("257			or ("257/761") or ("257/761") or		
or ("361/306.1") or ("361/306.3") or ("361/31"). CCLS.) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) nearl2 (tantalum adj oxide) or ("257/300") or ("257/300") or ("257/300") or ("257/310") or ("257/310") or ("257/310") or ("257/311") or ("257/310") or ("361/305") or ("361/306.1") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/306.3") or ("361/306.3") or ("361/301"			("25///63") or ("361/303") or ("361/305")		
("361/31").CCLS.) and (electrode same indium adj oxide) and (insulating or insulator or dielectric) nearl2 (tantalum adj oxide) or tantalum adj pentoxide)   ((("257/66") or ("257/306") or ("257/308") or ("257/309") or ("257/308") or ("361/306.") or ("257/308") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("361/306.") or ("257/730") or ("257/730") or ("257/730") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("361/306.") or ("361/306.") or ("361/306.") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("361/306.") or ("3			or ("361/306.1") or ("361/306.3") or		
indium adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide or tantalum adj pentoxide)  0 ((("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/305") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("361/306.]") or ("357/300") or ("257/300") or		İ	("361/311")).CCLS.) and (electrode same		
Insulator or dielectric) near12 (tantalum adj oxide or tantalum adj pentoxide)   0 ((("257/68") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/301") or ("361/303") or ("361/305") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("357/68") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/303.3") or ("361/305") or ("361/301")).CCLS.) and (electrode same indium adj oxide) and (dram or capacitor).tip nearl2 (tantalum adj oxide or tantalum adj electrode same indium adj oxide or tantalum adj electrode same indium adj oxide or tantalum adj electrode same indium adj oxide or tantalum adj electrode same indium adj oxide or tantalum adj electrode same indium adj oxide) and ((insulating or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/306.1") or ("361/306.3") or ("361/305.") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3"		İ	indium adj oxide) and ((insulating or		
adj oxide or tantalum adj pentoxide)   0 (("257/69") or ("257/71") or ("257/72")   0 ("257/730") or ("257/730") or ("257/730") or ("257/30") or ("257/30") or ("257/30") or ("257/311") or ("257/30") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("257/730") or ("361/307.1") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/306.1") or ("361/		}	insulator or dielectric popular (		
0 (("257/56") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("361/305") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/306.3") or ("361/306.3") or ("257/36") or ("257/36") or ("257/36") or ("257/36") or ("257/306") or ("257/306") or ("257/306") or ("257/30") or ("257/306") or ("257/30") or ("257/30") or ("361/306.3") or ("361/306.1") or ("361/305.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306			adi ovide or tantalum		
OF ("257/308") or ("257/306") or ("257/310") or ("257/310") or ("257/310") or ("257/310") or ("361/303") or ("361/305") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/301")).CCLS.) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide) or ("257/306") or ("257/300") or ("257/306") or ("257/300") or ("257/306") or ("257/30") or ("361/305.3") or ("361/301")).CCLS.) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide) or ("257/306") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("361/305") or ("361/305.1") or ("361/306.1") or ("361/305.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or		0	((("257/69") on ("257/71")		
("257/308") or ("257/309") or ("257/310") or ("257/311") or ("257/313") or ("361/305") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("351/308") or ("357/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/309") or ("257/310") or ("257/311") or ("351/306.3") or ("361/305.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/306.1") or ("361/307) or ("361/308") or ("361/308") or ("361/308") or ("361/308") or ("361/308") or ("361/308") or ("361/308") or ("361/308") or ("361/308") or ("361/308") or ("361/308") or ("361/308") or ("257/310") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("257/30") or ("361/308") or ("361/3			("257/296") or ("257/296")	USPAT;	2001/12/10 15:17
Cash, 1988   Or ("257/761") or ("257/763") or ("361/303") or ("361/305") or ("361/306.1") or ("361/303") or ("361/306.1") or ("361/306.3") or ("361/311")).CCLS.) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide or tantalum adj pentoxide)) and (("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/305.") or ("361/305.") or ("361/305.") or ("361/301.")).CCLS.) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide or tantalum adj pentoxide)) and (dram or capacitor) (("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/303") or ("361/305") or ("361/301").CCLS.) and (electrode same indium adj oxide or tantalum adj pentoxide)) and (dram or capacitor) (("257/68") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/303") or ("361/305") or ("361/301").CCLS.) and ((reductive or protection or protecting or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection)  10 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  10 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  20 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  20 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  20 (protecting or protection) cropped protection or protecting or protection or protecting or protection) cropped protection or protecting or protection or protecting or protecting or protecting or protec			or ("257/300") or ("257/306") or	US-PGPUB;	
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("257/763") or ("361/305") or ("361/305") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/311")).CCLS.) and (electrode same indium adj oxide) and (dram or capacitor).ti,ab.   (("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/301") or ("257/308") or ("361/306.1") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("361/301") or ("257/68") or ("257/68") or ("257/300") or ("361/303") or ("361/305")			or ("257/311") or ("257/761") or	DERWENT	1
or ("361/301.") or ("361/306.3") or ("361/311")).CCLS.) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) nearl2 (tantalum adj oxide) and ((dram or capacitor).ti,ab.  (("257/68") or ("257/306") or ("257/306") or ("257/300") or ("257/306") or ("257/300") or ("257/306") or ("257/307) or ("257/307) or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/30131")).CCLS.) and (electrode same indium adj oxide) and (dram or capacitor)  (("257/68") or ("257/71") or ("257/296") or ("257/68") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("257/308") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.1") or ("361/306.3") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.3") or ("361/306.1") or ("361/306.3") or ("361/306.3") or ("361/306.1") or ("361/306.3") or (			("257/763") or $("361/303")$ or $("361/305")$	1	
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Insulator or dielectric) near12 (tantalum adj oxide or tantalum adj pentoxide)) and (dram or capacitor).ti,ab.  0 ((("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/306") or ("257/308") or ("257/310") or ("257/311") or ("257/310") or ("257/311") or ("257/311") or ("257/311") or ("361/303") or ("361/305") or ("361/306.1") or ("361/306.3") or ("361/301"). CCLS.) and (electrode same indium adj oxide) and (dram or capacitor)  0 ((("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/306") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("361/305") or ("361/305.1") or ("361/303") or ("361/305") or ("361/306.3") or ("361/305") or ("361/306.1") or ("361/306.3") or ("361/301"). CCLS.) and (lreductive or protection or protection or protecting or protect) same tantalum adj nitride same indium adj oxide)  0 (tantalum adj nitride near12 indium adj oxide) same (protect or protection or protecting or protection)  10 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  10 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  10 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  11			indium adi oxide) and (/inquisting		ļ
adj oxide or tantalum adj pentoxide) and (dram or capacitor).ti,ab.		i	insulator or disloctrick		
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Or ("257/308") or ("257/306") or ("257/308") or ("257/308") or ("257/31") or ("361/303") or ("361/306.1") or ("361/306.3") or ("361/306.3") or ("361/311")).CCLS.) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide) or ("257/308") or ("257/308") or ("257/309") or ("257/308") or ("257/309") or ("257/308") or ("257/309") or ("257/309") or ("257/309") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/306.3") or ("361/301")).CCLS.) and ((reductive or protection or protecting or protect) same tantalum adj nitride same indium adj oxide) (tantalum adj nitride near12 indium adj oxide) same (protect or protection or protecting or protection)    0			(dram or capacitor).ti,ab.		
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("257/763") or ("361/303") or ("361/305") or ("361/306.1") or ("361/306.3") or ("361/311")).CCLS.) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) nearl2 (tantalum adj oxide or tantalum adj pentoxide)) and (dram or capacitor)    (("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/300") or ("257/301") or ("257/761") or ("257/763") or ("361/303") or ("361/305") or ("361/301")).CCLS.) and (reductive or protection or protection or protecting or protect) same tantalum adj nitride same indium adj oxide) (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection)    1			or ("257/311") or ("257/761") or		
or ("361/311")).CCLS.) and (electrode same indium adj oxide) and ((insulating or insulator or dielectric) near12 (tantalum adj oxide or tantalum adj pentoxide)) and (dram or capacitor)  (("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/300") or ("257/300") or ("257/301") or ("257/311") or ("257/761") or ("257/763") or ("361/303") or ("361/305") or ("361/301")).CCLS.) and ((reductive or protection or protection or protecting or protect) same tantalum adj nitride same indium adj oxide)  (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection or protecting or protection)  at antalum adj nitride same indium adj oxide  tantalum adj nitride same indium adj oxide  tantalum adj nitride same indium adj oxide  at antalum adj nitride same indium adj oxide  tantalum adj nitride same indium adj oxide  tantalum adj nitride same indium adj oxide  tantalum adj nitride same indium adj oxide  tantalum adj nitride same indium adj oxide  colorate variation and protection or protectio			("257/763") or ("361/303") or ("361/305")	1	
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Insulator or dielectric) near12 (tantalum adj oxide or tantalum adj pentoxide)) and (dram or capacitor)  0 ((("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/306") or ("257/308") or ("257/309") or ("257/310") or ("257/31") or ("257/763") or ("361/303") or ("361/306.1") or ("361/306.3") or ("361/311")).CCLS.) and ((reductive or protection or protection or protecting or protect) same tantalum adj nitride same indium adj oxide)  0 (tantalum adj nitride near12 indium adj oxide) same (protect or protection or protecting or protection)  0 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  10 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  10 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  10 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  10 (tantalum adj nitride same indium adj oxide) same (protect or protection or protecting or protection)  10 (tantalum adj nitride same indium adj oxide) uspāT; us-pGPUB; EPO; JPO; DERWENT; IEM TDB USPĀT; us-pGPUB; EPO; JPO; DERWENT; Us-pGPUB; EPO; JPO; DERWE			indiam add outdo) and (electrode same		
adjoxide or tantalum adj pentoxide)) and (dram or capacitor)  ((("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/300") or ("257/300") or ("257/308") or ("257/309") or ("257/310") or ("257/763") or ("361/303") or ("361/305") or ("361/306.1") or ("361/306.3") or ("361/311")).CCLS.) and ((reductive or protection or protecting or protect) same tantalum adj nitride same indium adjoxide) (tantalum adj nitride same indium adjoxide) same (protect or protection or protecting or protection)  (tantalum adj nitride same indium adjoxide) same (protect or protection or protecting or protection)  (tantalum adj nitride same indium adjoxide) same (protect or protection or protecting or protection)  (tantalum adj nitride same indium adjoxide) USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPĀT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPĀT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPĀT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPĀT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPĀT; US-PGPUB; EPO; JPO; DERWENT; EPO; JPO; DERWENT; EPO; JPO; DERWENT; EPO; JPO; DERWENT;			ingulator and ((insulating or	İ	1
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Or ("257/731") or ("257/761") or ("257/763") or ("361/303") or ("361/305") or ("361/306.3") or ("361/311")).CCLS.) and ((reductive or prtoection or protecting or protect) same tantalum adj nitride same indium adj oxide)  Or (tantalum adj nitride near12 indium adj oxide) same (protect or protection or protecting or protection)  Or (tantalum adj nitride same indium adj oxide) same (protect or protection or protection)  Or (tantalum adj nitride same indium adj oxide) same (protect or protection or protection or protecting or protection)  33 tantalum adj nitride same indium adj oxide  Tantalum adj nitride same indium adj oxide  34 tantalum adj nitride same indium adj oxide  DERWENT;  IBM_TDB  USPAT;  US-PGPUB;  EPO; JPO;  DERWENT;  IBM_TDB  USPAT;  US-PGPUB;  EPO; JPO;  DERWENT;  IBM_TDB  USPAT;  US-PGPUB;  EPO; JPO;  DERWENT;  DERWENT;			("257/308") or ("257/309") or ("257/310")	US-PGPUB;	
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-	1815	("361/311")).CCLS.) and capacitor.ti, ab. and (electrode near12 indium oxide) ((("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/306") or ("257/308") or ("257/308") or ("257/310") or ("257/311") or ("257/761") or ("257/763") or ("361/303") or ("361/306.3") or ("361/306.3") or	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/12/10 15:44
-	1815	("361/311")).CCLS.) and capacitor.ti,ab. and (electrode near4 indium oxide) ((("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/306") or ("257/308") or ("257/310") or ("257/311") or ("257/761") or ("257/763") or ("361/303") or ("361/305")	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2001/12/10 15:44
-	1	or ("361/306.1") or ("361/306.3") or ("361/311")).CCLS.) and capacitor.ti,ab. and (electrode near2 indium oxide) ((("257/68") or ("257/71") or ("257/296") or ("257/300") or ("257/308") or ("257/308") or ("257/309") or ("257/310") or ("257/311") or ("257/761") or ("257/763") or ("361/303") or ("361/305") or ("361/306.1") or ("361/306.3") or	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2001/12/10 15:44
		("361/311")).CCLS.) and capacitor.ti,ab. and (electrode near2 indium adj oxide) hdp near3 silicon adj substrate	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/07/12 10:16